

MC100ELT23

5V Dual Differential PECL to TTL Translator

The MC100ELT23 is a dual differential PECL to TTL translator. Because PECL (Positive ECL) levels are used, only +5 V and ground are required. The small outline 8-lead package and the dual gate design of the ELT23 makes it ideal for applications which require the translation of a clock and a data signal.

The PECL inputs are differential; therefore, the MC100ELT23 can accept any standard differential PECL input referenced from a V_{CC} of 5.0 V.

- 3.5 ns Typical Propagation Delay
- 24 mA TTL Outputs
- Flow Through Pinouts
- ESD Protection: >2 KV HBM, > 400 V MM
- The 100 Series Contains Temperature Compensation
- Operating Range V_{CC} = 4.75 V to 5.25 V with GND = 0 V
- Internal Input Pulldown Resistors
- Q Output Will Default High with Inputs Left Open or < 1.3 V
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
- For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 91 devices

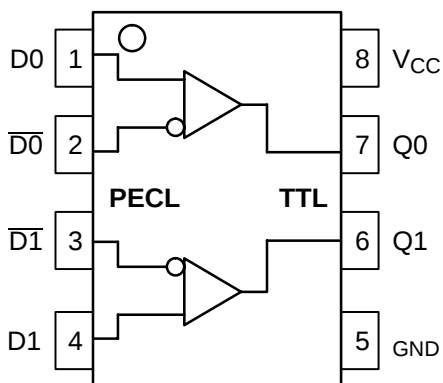


Figure 1. 8-Lead Pinout and Logic Diagram
(Top View)

PIN DESCRIPTION

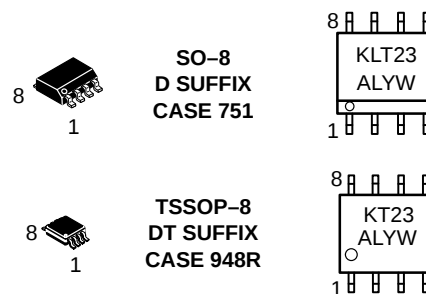
PIN	FUNCTION
Qn	TTL Outputs
Dn, $\overline{Dn}$	PECL Differential Inputs
V_{CC}	Positive Supply
GND	Ground



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MARKING DIAGRAMS*



A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

*For additional information, see Application Note AND8002/D

ORDERING INFORMATION

Device	Package	Shipping
MC100ELT23D	SO-8	98 Units / Rail
MC100ELT23DR2	SO-8	2500 / Reel
MC100ELT23DT	TSSOP-8	98 Units / Rail
MC100ELT23DTR2	TSSOP-8	2500 / Reel

MC100ELT23

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	Power Supply	GND = 0 V		7	V
V _I	Input Voltage	GND = 0 V	V _I ≤ V _{CC}	0 to 6	V
T _A	Operating Temperature Range			−40 to +85	°C
T _{stg}	Storage Temperature Range			−65 to +150	°C
θ _{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W
θ _{JC}	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
θ _{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W
θ _{JC}	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44 ± 5%	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

1. Maximum Ratings are those values beyond which device damage may occur.

PECL INPUT DC CHARACTERISTICS V_{CC}= 5.0 V; GND= 0.0 V (Note 2)

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V _{IH}	Input HIGH Voltage (Single Ended)	3835		4120	3835		4120	3835		4120	mV
V _{IL}	Input LOW Voltage (Single Ended)	3190		3525	3190		3525	3190		3525	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 3)	2.2		5.0	2.2		5.0	2.2		5.0	V
I _{IH}	Input HIGH Current			150			150			150	μA
I _{IL}	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

2. Input parameters vary 1:1 with V_{CC}. V_{CC} can vary ± 0.25 V.

3. V_{IHCMR} min varies 1:1 with GND, V_{IHCMR} max varies 1:1 with V_{CC}.

TTL OUTPUT DC CHARACTERISTICS V_{CC} = 4.75V to 5.25V; T_A = −40°C to 85°C

Symbol	Characteristic	Condition	Min	Typ	Max	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = −3.0 mA	2.4		(Note 4)	V
V _{OL}	Output LOW Voltage	I _{OL} = 24 mA			0.5	V
I _{CCH}	Power Supply Current			23	33	mA
I _{CCL}	Power Supply Current			26	36	mA
I _{OS}	Output Short Circuit Current		−150		−60	mA

4. Max level is V_{CC}−0.7 V by design.

AC CHARACTERISTICS V_{CC}= 5.0 V; GND= 0.0 V (Note 5 and Note 6.)

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f _{max}	Maximum Toggle Frequency		TBD			TBD			TBD		MHz
t _{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t _{PLH}	Propagation Delay @ 1.5 V C _L = 20 pF	2.0		5.5	2.0		5.5	2.0		5.5	ns
t _{PHL}	Propagation Delay @ 1.5 V C _L = 20 pF	2.0		5.5	2.0		5.5	2.0		5.5	ns
V _{PP}	Input Swing (Note 7)	200		1000	200		1000	200		1000	mV
t _r /t _f	Output Rise Time (10–90%) C _L = 20pF					1.6					ns
	Output Fall Time (10–90%) C _L = 20pF					1.1					ns

5. V_{CC} can vary ± 0.25 V.

6. All loading with 500 ohms to GND, C_L = 20 pF.

7. V_{PP}(min) is the minimum input swing for which AC parameters are guaranteed. The device has a DC gain of ≈40.

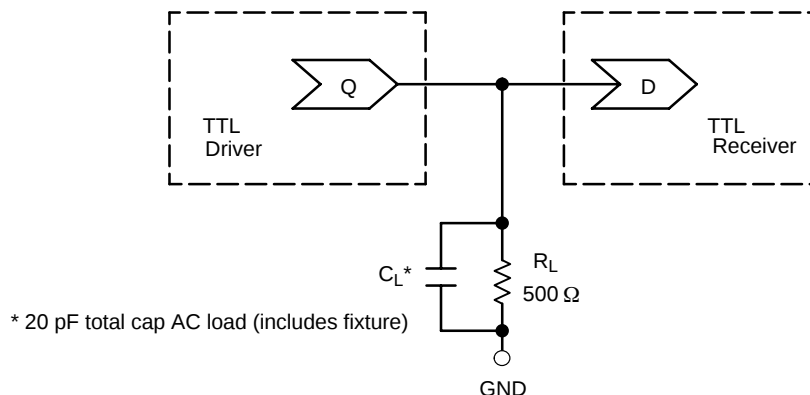


Figure 2. TTL Output Loading Used for Device Evaluation

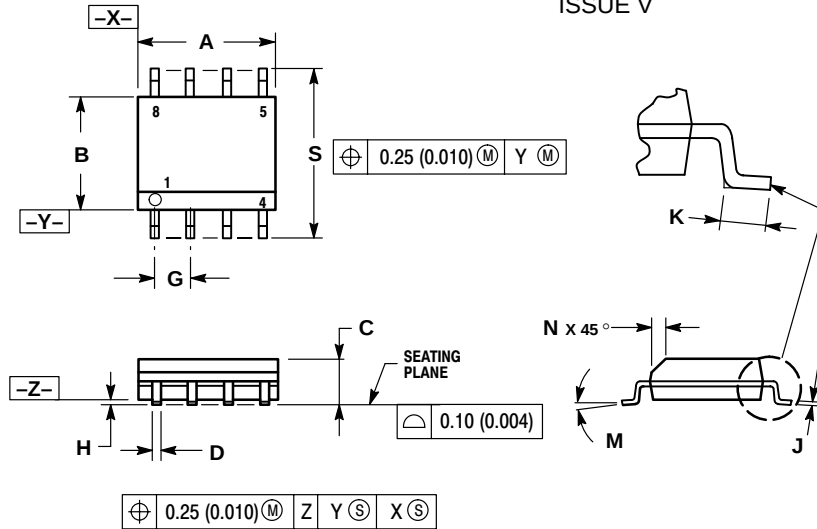
Resource Reference of Application Notes

- AN1404** – ECLinPS Circuit Performance at Non–Standard V_{IH} Levels
- AN1405** – ECL Clock Distribution Techniques
- AN1406** – Designing with PECL (ECL at +5.0 V)
- AN1503** – ECLinPS I/O SPICE Modeling Kit
- AN1504** – Metastability and the ECLinPS Family
- AN1560** – Low Voltage ECLinPS SPICE Modeling Kit
- AN1568** – Interfacing Between LVDS and ECL
- AN1596** – ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
- AN1650** – Using Wire–OR Ties in ECLinPS Designs
- AN1672** – The ECL Translator Guide
- AND8001** – Odd Number Counters Design
- AND8002** – Marking and Date Codes
- AND8020** – Termination of ECL Logic Devices

MC100ELT23

PACKAGE DIMENSIONS

SO-8
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751-07
ISSUE V



NOTES:

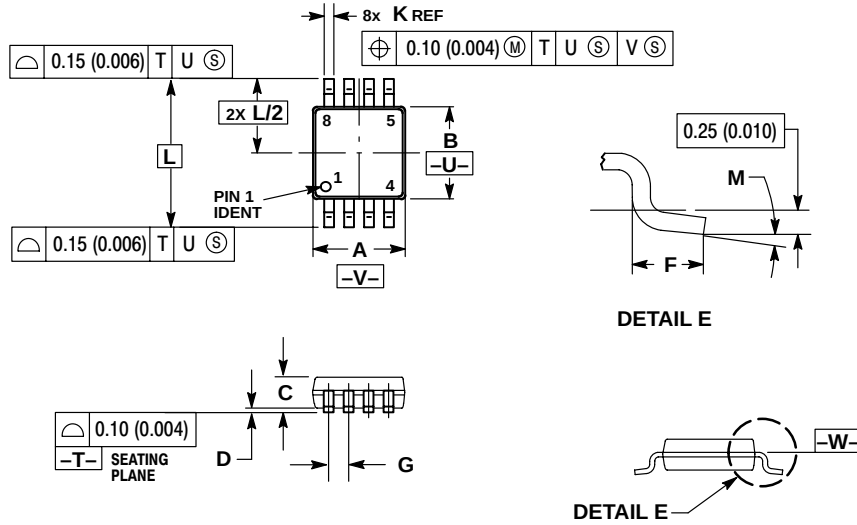
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

MC100ELT23

PACKAGE DIMENSIONS

TSSOP-8
DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948R-02
ISSUE A



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0°	6°	0°	6°

Notes

Notes

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